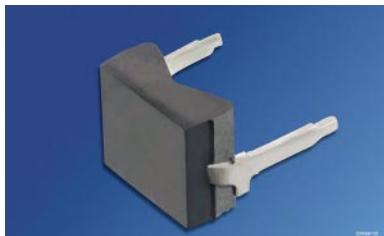


# **Si-PIN-Fotodiode mit Tageslichtsperrfilter; in SMT und als Reverse Gullwing Silicon PIN Photodiode with Daylight Filter; in SMT and as Reverse Gullwing**

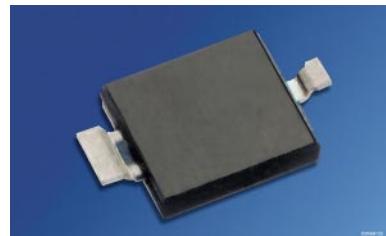
## **BPW 34 FA, BPW 34 FAS, BPW 34 FAS (E9087)**



BPW 34 FA



BPW 34 FAS



BPW 34 FAS (E9087)

### **Wesentliche Merkmale**

- Speziell geeignet für den Wellenlängenbereich von 830 nm bis 880 nm
- Kurze Schaltzeit (typ. 20 ns)
- DIL-Plastikbauförm mit hoher Packungsdichte
- BPW 34 FAS/(E9087): geeignet für Vapor-Phase Löten und IR-Reflow Löten

### **Anwendungen**

- IR-Fernsteuerung von Fernseh- und Rundfunkgeräten, Videorecordern, Gerätefernsteuerung
- Lichtschranken für Gleich- und Wechsellichtbetrieb

### **Features**

- Especially suitable for the wavelength range of 830 nm to 880 nm
- Short switching time (typ. 20 ns)
- DIL plastic package with high packing density
- BPW 34 FAS/(E9087): Suitable for vapor-phase and IR-reflow soldering

### **Applications**

- IR-remote control of hi-fi and TV sets, video tape recorders, remote controls of various equipment
- Photointerrupters

Typ Type	Bestellnummer Ordering Code
BPW 34 FA	Q62702-P1129
BPW 34 FAS	Q62702-P463
BPW 34 FAS (E9087)	Q62702-P1829

**Grenzwerte**

**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}$ ; $T_{\text{stg}}$	- 40 ... + 100	°C
Sperrspannung Reverse voltage	$V_R$	32	V
Verlustleistung, $T_A = 25$ °C Total power dissipation	$P_{\text{tot}}$	150	mW

**Kennwerte ( $T_A = 25$  °C,  $\lambda = 870$  nm)**

**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Fotostrom Photocurrent $V_R = 5$ V, $E_e = 1$ mW/cm <sup>2</sup>	$I_p$	50 ( $\geq 40$ )	µA
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S \text{ max}}$	880	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{\text{max}}$ Spectral range of sensitivity $S = 10\%$ of $S_{\text{max}}$	$\lambda$	730 ... 1100	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	$A$	7.00	mm <sup>2</sup>
Abmessung der bestrahlungsempfindlichen Fläche Dimensions of radiant sensitive area	$L \times B$ $L \times W$	2.65 × 2.65	mm × mm
Halbwinkel Half angle	$\phi$	± 60	Grad deg.
Dunkelstrom, $V_R = 10$ V Dark current	$I_D$	2 ( $\leq 30$ )	nA
Spektrale Fotoempfindlichkeit Spectral sensitivity	$S_\lambda$	0.65	A/W
Quantenausbeute Quantum yield	$\eta$	0.93	Electrons Photon
Leerlaufspannung, $E_e = 0.5$ mW/cm <sup>2</sup> Open-circuit voltage	$V_O$	320 ( $\geq 250$ )	mV

# BPW 34 FA, BPW 34 FAS, BPW 34 FAS (E9087)

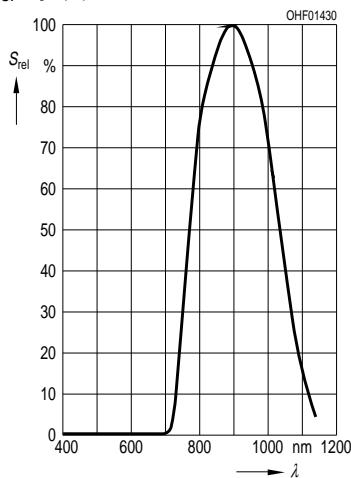
**Kennwerte ( $T_A = 25^\circ\text{C}$ ,  $\lambda = 870 \text{ nm}$ )**

**Characteristics (cont'd)**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Kurzschlußstrom, $E_e = 0.5 \text{ mW/cm}^2$ Short-circuit current	$I_{SC}$	23	$\mu\text{A}$
Anstiegs- und Abfallzeit des Fotostromes Rise and fall time of the photocurrent $R_L = 50 \Omega$ ; $V_R = 5 \text{ V}$ ; $\lambda = 850 \text{ nm}$ ; $I_p = 800 \mu\text{A}$	$t_r, t_f$	20	ns
Durchlaßspannung, $I_F = 100 \text{ mA}$ , $E = 0$ Forward voltage	$V_F$	1.3	V
Kapazität, $V_R = 0 \text{ V}$ , $f = 1 \text{ MHz}$ , $E = 0$ Capacitance	$C_0$	72	pF
Temperaturkoeffizient von $V_O$ Temperature coefficient of $V_O$	$TC_V$	- 2.6	mV/K
Temperaturkoeffizient von $I_{SC}$ Temperature coefficient of $I_{SC}$	$TC_I$	0.03	%/K
Rauschäquivalente Strahlungsleistung Noise equivalent power $V_R = 10 \text{ V}$	$NEP$	$3.9 \times 10^{-14}$	$\frac{\text{W}}{\sqrt{\text{Hz}}}$
Nachweisgrenze, $V_R = 10 \text{ V}$ , Detection limit	$D^*$	$6.8 \times 10^{12}$	$\frac{\text{cm} \times \sqrt{\text{Hz}}}{\text{W}}$

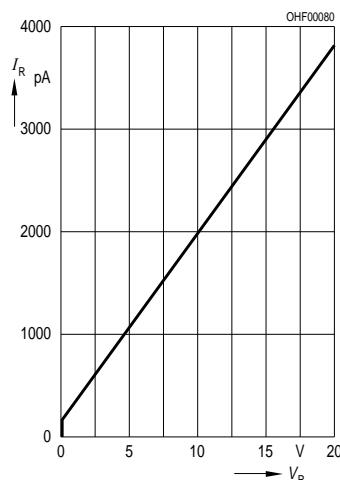
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**Relative Spectral Sensitivity**  
 $S_{\text{rel}} = f(\lambda)$



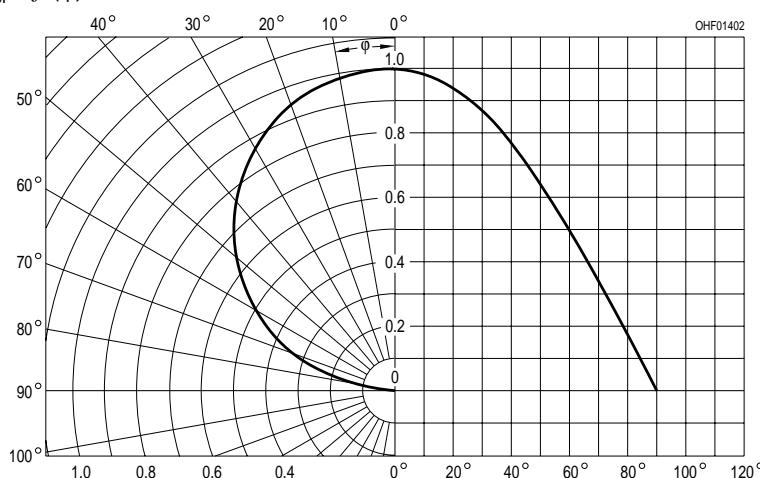
**Dark Current**

$$I_R = f(V_R), E = 0$$

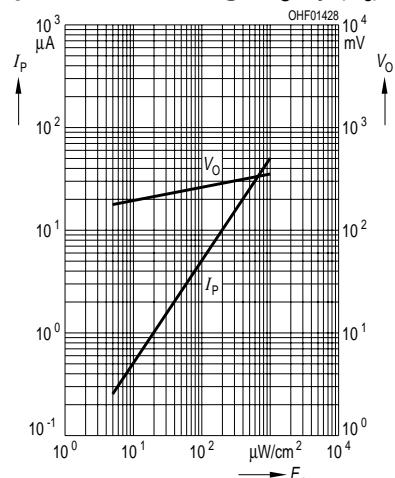


**Directional Characteristics**

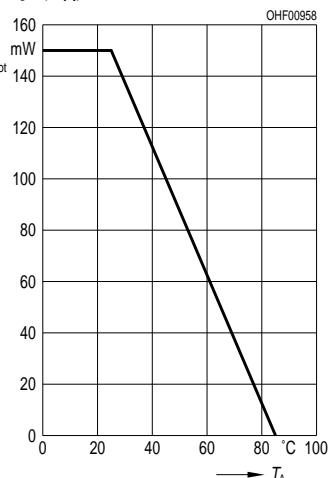
$$S_{\text{rel}} = f(\phi)$$



**Photocurrent**  $I_P = f(E_e)$ ,  $V_R = 5 \text{ V}$   
**Open-Circuit Voltage**  $V_O = f(E_e)$

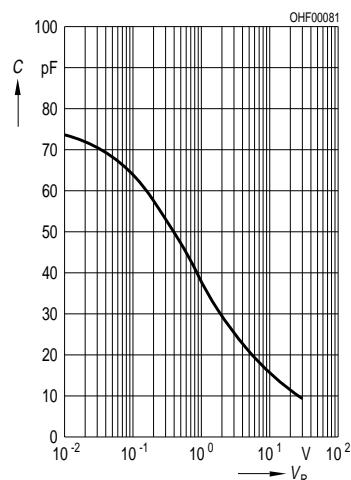


**Total Power Dissipation**  
 $P_{\text{tot}} = f(T_A)$



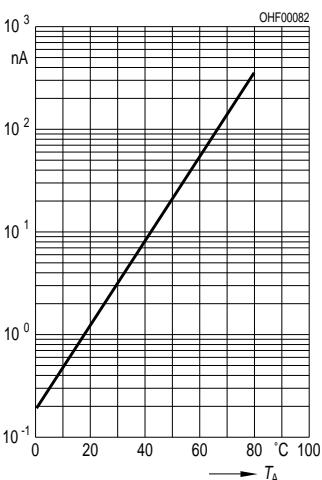
**Capacitance**

$$C = f(V_R), f = 1 \text{ MHz}, E = 0$$



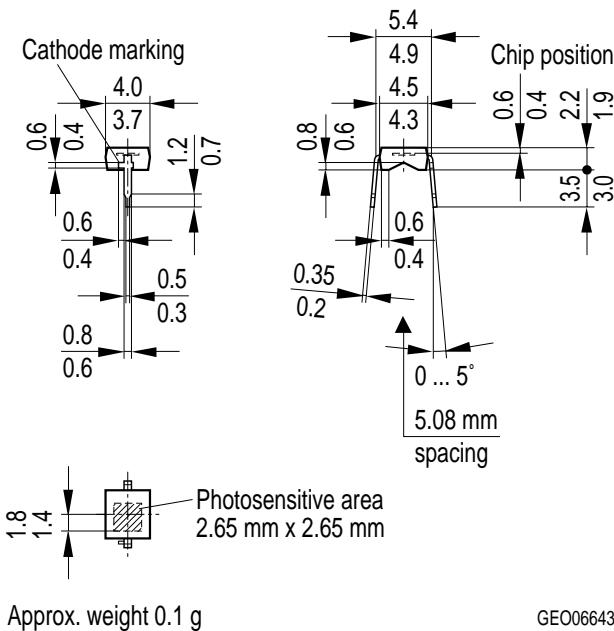
**Dark Current**

$$I_R = f(T_A), V_R = 10 \text{ V}, E = 0$$

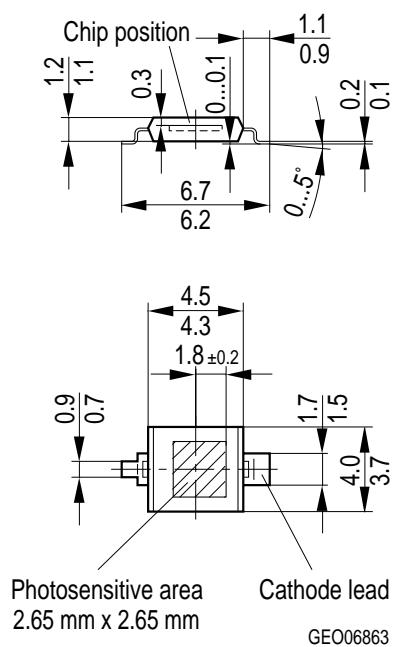


**Maßzeichnung  
Package Outlines**

BPW 34 FA



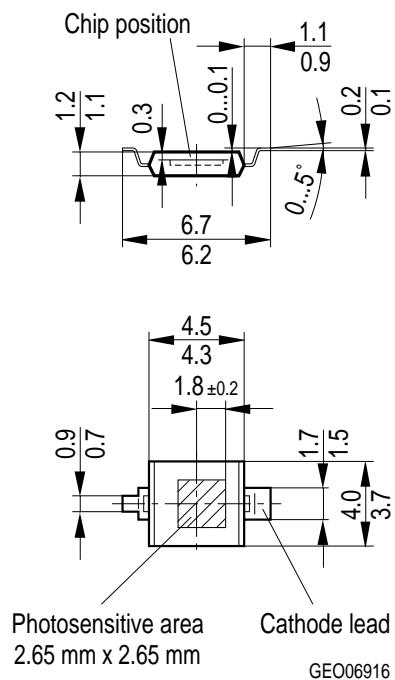
BPW 34 FAS



Maße in mm, wenn nicht anders angegeben / Dimensions in mm, unless otherwise specified.

# BPW 34 FA, BPW 34 FAS, BPW 34 FAS (E9087)

BPW 34 FAS (E9087)



Maße in mm, wenn nicht anders angegeben / Dimensions in mm, unless otherwise specified.